

查询1N753A-1供应商

捷多邦, 专业PCB打样工厂, 24小时

加急出货

Microsemi Corp.

The diode experts

SCOTTSDALE, AZ

For more information call:
(602) 941-6300

1N759A, -1
and
1N4370 thru
1N4372A, -1
DO-35

1% and 2% VERSIONS
"C" and "D" AVAILABLE

FEATURES

- ZENER VOLTAGE 2.4V to 12.0V
- AVAILABLE IN JAN, JANTX and JANTXV-1 QUALIFICATIONS TO MIL-S-19500/127. DIE ALSO AVAILABLE AS JANHC FOR HYBRIDS.
- METALLURGICALLY BONDED DEVICE TYPES

MAXIMUM RATINGS

Junction and Storage Temperatures: -65°C to +175°C
DC Power Dissipation: 500 mW
Power Derating: 4.0 mW/°C above 50°C
Forward Voltage @ 200 mA: 1.5 Volts

* ELECTRICAL CHARACTERISTICS @ 25°C

JEDEC TYPE NO. (NOTE 1)	NOMINAL ZENER VOLTAGE V_Z @ I_{ZT} (NOTE 2) VOLTS	ZENER TEST CURRENT I_{ZT} mA	MAXIMUM ZENER IMPEDANCE Z_{ZT} @ I_{ZT} (NOTE 3) OHMS	MAXIMUM REVERSE CURRENT @ $V_R = 1$ VOLT		MAXIMUM ZENER CURRENT I_{ZW} (NOTE 4) mA	TYPICAL TEMP COEFF. OF ZENER VOLTAGE (V_{ZZ}) %/°C
				@ 25°C	@ +150°C		
				μA	μA		
1N4370	2.4	20	30	100	200	150	-085
1N4371	2.7	20	30	75	150	135	-080
1N4372	3.0	20	29	50	100	120	-075
1N746	3.3	20	28	10	30	110	-066
1N747	3.6	20	24	10	30	100	-058
1N748	3.9	20	23	10	30	95	-046
1N749	4.3	20	22	2	30	85	-033
1N750	4.7	20	19	2	30	75	-015
1N751	5.1	20	17	1	20	70	± 010
1N752	5.6	20	11	1	20	65	+030
1N753	6.2	20	7	.1	20	60	+049
1N754	6.8	20	5	.1	20	55	+053
1N755	7.5	20	6	.1	20	50	+057
1N756	8.2	20	8	.1	20	45	+060
1N757	9.1	20	10	.1	20	40	+061
1N758	10.0	20	17	.1	20	35	+062
1N759	12.0	20	30	.1	20	30	+062

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NOTE 1 Standard tolerance on JEDEC types shown is $\pm 10\%$. Suffix letter A denotes $\pm 5\%$ tolerance; suffix letter C denotes $\pm 2\%$; and suffix letter D denotes $\pm 1\%$ tolerance.

NOTE 2 Voltage measurements to be performed 20 sec. after application of D. C. test current.

NOTE 3 Zener impedance derived by superimposing on I_{ZT} , a 60 cps, rms ac current equal to $10\% I_{ZT}$ (2 mA ac).

NOTE 4 Allowance has been made for the increase in V_Z due to Z_Z and for the increase in junction temperature as the unit approaches thermal equilibrium at the power dissipation of 400 mW.

SILICON
500 mW
ZENER DIODES

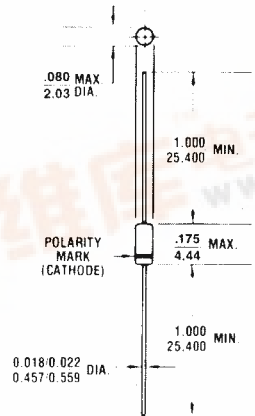


FIGURE 1

All dimensions in
INCH
m.m.

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case. DO-35.

FINISH: All external surfaces are corrosion resistant and leads solderable.

THERMAL RESISTANCE: 200°C/W (Typical) junction to lead at 0.375-inches from body. Metallurgically bonded DO-35's exhibit less than 100 °C/W at zero distance from body.

POLARITY: Diode to be operated with the banded end positive with respect to the opposite end.

WEIGHT: 0.2 grams.

MOUNTING POSITIONS: Any.

1N746 thru 1N759A, -1 DO-35
1N4370 thru 1N4372A, -1

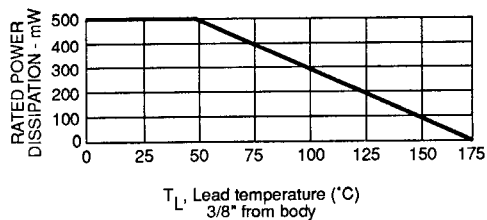


FIGURE 2 POWER DERATING CURVE

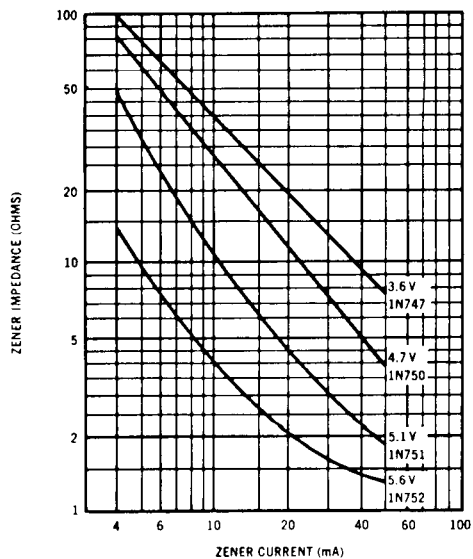


FIGURE 3

ZENER IMPEDANCE VS ZENER CURRENT
(TYPICAL)

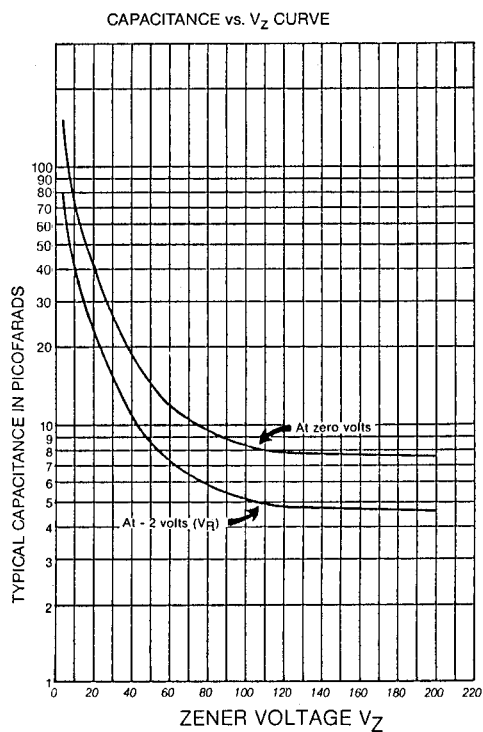


FIGURE 4

CAPACITANCE VS. ZENER VOLTAGE
(TYPICAL)